

## **SiC Schottky Barrier Diodes**

SCS112AG

### [ Product description ]

Switching loss reduced, enabling high-speed switching . (2-pin package)

## **Features**

- Shorter recovery time
- Reduced temperature dependence
- High-speed switching possible

## **Product specifications**

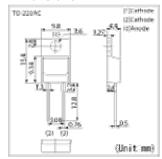
Absolute maximum ratings (Ta=25°C)		
Rated parameters	Standard value	Conditions
Repetitive peak reverse voltage $V_{RM}(V)$	600	
Reverse voltage(DC) V <sub>R</sub> (V)	600	
Average rectified forward current I <sub>O</sub> (A)	12	
Forward current surge peak I <sub>FSM</sub> (A)	48	60Hz/1cyc
Junction temperature Tj(°C)	150	
Storage temperature Tstg(°C)	-55 to +150	

#### **Outline**



9.8x15.4(t=4.4)

#### **Dimensions**



# Equivalent circuit diagram



<sup>\*</sup>The contents described here are just outline for introduction.

Please obtain the specification sheets from us for thorough check before use.

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